## NSN 5962-01-391-0611

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high to low level

View Online at https://aerobasegroup.com/nsn/5962-01-391-0611

Body Length:	
0.540 inches	
Body Width:	
0.300 inches	
Body Height:	
0.092 inches	
Maximum Power	Dissipation Rating:
1.0 watts	
Operating Tempu	rature Range:
-55.0/+125.0 degre	es celsius
Storage Tempura	ture Range:
-65.0/+150.0 degre	es celsius
Features Provide	d:
Hermetically seale	d and burn in and programmable and positive outputs
Inclosure Materia	l:
Ceramic and glass	
Inclosure Configu	uration:
Flat pack	
Output Logic For	m:
Transistor-transiste	or logic
Input Circuit Patte	ern:
16 input	
Criticality Code J	ustification:
Feat	
Case Outline Sou	Irce And Designator:
F-9 mil-m-38510	
Terminal Surface	Treatment:
Solder	
Voltage Rating A	nd Type Per Characteristic:
	ource and 7.0 volts power source
Time Rating Per (	
_	ls propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time,
output	
Memory Device T	vpe:
Pal	,F
Special Features:	
-	no: 8907815-1-701, using module pmi-803063, cpu/rc 8905830 and location u31
Test Data Docum	
	standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type Ar	
20 flat leads	
Shelf Life:	
Shell Life.	

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Unit Of Measure:

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Demilitarization:

No

Fiig:

A458a0

